



#### PNP PRE-BIASED TRANSISTOR IN SOT23

#### **Features**

- Epitaxial Planar Die Construction
- Built-In Biasing Resistors
- Surface Mount Package Suited for Automated Assembly
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <a href="https://www.diodes.com/quality/product-definitions/">https://www.diodes.com/quality/product-definitions/</a>

Part Number	R1(NOM)	R2(NOM)
DDTB113EC	1kΩ	1kΩ
DDTB123EC	2.2kΩ	2.2kΩ
DDTB143EC	4.7kΩ	4.7kΩ
DDTB114EC	10kΩ	10kΩ
DDTB122JC	0.22kΩ	4.7kΩ
DDTB113ZC	1kΩ	10kΩ
DDTB123YC	2.2kΩ	10kΩ
DDTB133HC	3.3kΩ	10kΩ
DDTB123TC	2.2kΩ	Open
DDTB143TC	4.7kΩ	Open
DDTB114TC	10kΩ	Open
DDTB114GC	0	10kΩ

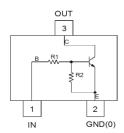




Top View

### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound;
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (Approximate)



**Device Schematic** 

### Ordering Information (Note 4)

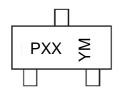
Part Number	Status	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DDTB113EC-7-F	Obsolete	Standard	P60	7	8	3,000
DDTB123EC-7-F	Obsolete	Standard	P61	7	8	3,000
DDTB143EC-7-F	Obsolete	Standard	P62	7	8	3,000
DDTB114EC-7-F	Active	Standard	P63	7	8	3,000
DDTB122JC-7-F	Obsolete	Standard	P64	7	8	3,000
DDTB113ZC-7-F	Active	Standard	P65	7	8	3,000
DDTB123YC-7-F	Active	Standard	P66	7	8	3,000
DDTB133HC-7-F	Obsolete	Standard	P67	7	8	3,000
DDTB123TC-7-F	Obsolete	Standard	P69	7	8	3,000
DDTB143TC-7-F	Obsolete	Standard	P70	7	8	3,000
DDTB114TC-7-F	Obsolete	Standard	P71	7	8	3,000
DDTB114GC-7-F	Obsolete	Standard	P72	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



### **Marking Information**



PXX = Product Type Marking Code YM = Date Code Marking Y = Year (ex: I = 2021) M = Month (ex: 9 = September)

Date Code Key

Year	2010		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	Χ			J	K	L	М	N	0	Р	R	S
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

## Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Charac	cteristic	Symbol	Value	Unit
Supply Voltage, (3) to (2)		Vcc	-50	V
Input Voltage, (1) to (2)	DDTB113EC DDTB123EC DDTB143EC DDTB114EC DDTB122JC DDTB113ZC DDTB123YC DDTB133HC	Vin	+10 to -10 +10 to -12 +10 to -30 +10 to -40 +5 to -5 +5 to -10 +5 to -12 +6 to -20	V
Input Voltage, (1) to (2)	DDTB123TC DDTB143TC DDTB114TC DDTB114GC	V <sub>EBO</sub> (MAX)	-5	V
Output Current	All	Ic	-500	mA

# Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	200	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	RθJA	625	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Note: 5. Mounted on FR4 PC Board with minimum recommended pad layout.



Electrical Characteristics (@TA = +25°C, unless otherwise specified.) R1, R2 Types

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Input Valtage	DDTB113EC DDTB123EC DDTB143EC DDTB114EC DDTB122JC DDTB113ZC DDTB123YC DDTB133HC	V <sub>I</sub> (off)	-0.5 -0.5 -0.5 -0.5 -0.5 -0.3 -0.3	_	_	V	Vcc = -5V, Io = -100μA
Input Voltage	DDTB113EC DDTB123EC DDTB143EC DDTB114EC DDTB122JC DDTB113ZC DDTB123YC DDTB133HC	VI(on)	_	_	-3.0 -3.0 -3.0 -3.0 -3.0 -2.0 -2.0 -2.0	V	Vo = -0.3V, Io = -20mA Vo = -0.3V, Io = -20mA Vo = -0.3V, Io = -20mA Vo = -0.3V, Io = -10mA Vo = -0.3V, Io = -30mA Vo = -0.3V, Io = -20mA Vo = -0.3V, Io = -20mA Vo = -0.3V, Io = -20mA
Output Voltage		V <sub>O(on)</sub>		_	-0.3	V	$I_0/I_1 = -50 \text{mA}/-2.5 \text{mA}$
Input Current	DDTB113EC DDTB123EC DDTB143EC DDTB114EC DDTB122JC DDTB113ZC DDTB123YC DDTB133HC	lı		1	-7.2 -3.8 -1.8 -0.88 -28 -7.2 -3.6 -2.4	mA	Vı = -5V
Output Current	•	I <sub>O(off)</sub>		_	-0.5	μΑ	Vcc = -50V, Vi = 0V
DC Current Gain	DDTB113EC DDTB123EC DDTB143EC DDTB114EC DDTB122JC DDTB113ZC DDTB123YC DDTB133HC	Gı	33 39 47 56 47 56 56 56	_	_	_	V <sub>O</sub> = -5V, I <sub>O</sub> = -50mA
Gain-Bandwidth Product (Note 6)		f⊤	_	200	_	MHz	Vce = -10V, I <sub>E</sub> = -5mA, f = 100MHz

### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

### R1-Only, R2-Only Types

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		ВУсво	-50	_	_	V	Ic = -50μA
Collector-Emitter Breakdown Voltage		BVceo	-40	_	_	V	Ic = -1mA
Emitter-Base Breakdown Voltage DDTB123TC DDTB143TC DDTB114TC DDTB114GC		BV <sub>EBO</sub>	-5	_	_	V	IE = -50μA IE = -50μA IE = -50μA IE = -720μA
Collector Cutoff Current		I <sub>CBO</sub>	_	_	-0.5	μΑ	V <sub>CB</sub> = -50V
Emitter Cutoff Current	DDTB123TC DDTB143TC DDTB114TC DDTB114GC	I <sub>EBO</sub>	   -300		-0.5 -0.5 -0.5 -580	μΑ	V <sub>EB</sub> = -4V
Collector-Emitter Saturation Voltage		VCE(sat)			-0.3	V	Ic = -50mA, I <sub>B</sub> = -2.5mA
DC Current Transfer Ratio	DDTB123TC DDTB143TC DDTB114TC DDTB114GC	hFE	100 100 100 56	250 250 250 —	600 600 600	_	Ic = -5mA, VcE = -5V
Gain-Bandwidth Product (Note 6)		f⊤	_	200	_	MHz	VcE = -10V, IE = -5mA, f = 100MHz

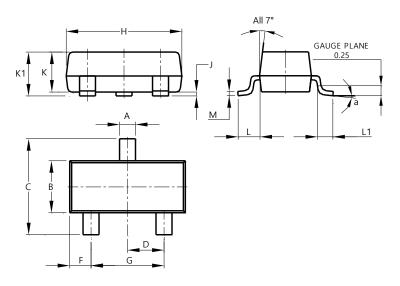
Note: 6. Transistor - For Reference Only.



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23

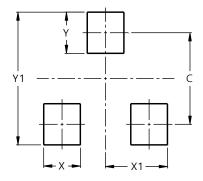


SOT23								
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
C	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
7	0.013	0.10	0.05					
K	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
а	0°	8°						
All	Dimens	ions in	mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	29



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